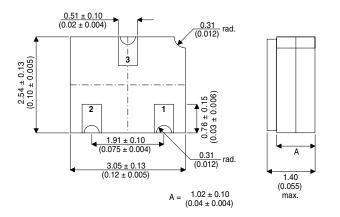
FMMT92CSM



MECHANICAL DATA

Dimensions in mm (inches)



SOT23 CERAMIC (LCC1 PACKAGE)

Underside View

GENERAL PURPOSE PNP TRANSISTOR IN A HERMETICALLY SEALED CERAMIC SURFACE MOUNT PACKAGE

FEATURES

- GENERAL PURPOSE PNP TRANSISTOR
- HERMETIC CERAMIC SURFACE MOUNT PACKAGE
- CECC SCREENING OPTIONS

PAD 1 – Base PAD 2 – Emitter PAD 3 – Collector

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

V _{CBO}	Collector – Base Voltage	-300V		
V _{CEO}	Collector – Emitter Voltage	-300V		
V_{EBO}	Emitter – Base Voltage	-5V		
I _C	Continuous Collector Current	-500mA		
P _{tot}	Power Dissipation @ $T_{amb} = 25^{\circ}C$	680mW		
	$@ T_{case} = 25^{\circ}C$	1.8W		
T _j T _{stg}	Operating and Storage Temperature	–55 to 175°C		

THERMAL CHARACTERISTICS

Parameter	Max.	Unit
Rth(j-amb) Thermal Resistance Junction to Ambient	350	°C/W
Rth(j-case) Thermal Resistance Junction to Case	80	°C/W

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V _{(BR)CBO}	Collector – Base Breakdown Voltage	I _C = -100μA	I _E = 0	-300			V
V _{(BR)CEO}	Collector - Emitter Breakdown Voltage	I _C = -1mA*	I _B = 0	-300			V
V _{(BR)EBO}	Emitter – Base Breakdown Voltage	Ι _Ε = -10μΑ	$I_{\rm C} = 0$	-5			V
I _{CBO}	Collector Cut-off Current	V _{CB} = -200V	$I_E = 0$			-0.25	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -3V$	$I_E = 0$			-0.1	
V _{CE(sat)}	Collector – Emitter Saturation Voltage	I _C = -20mA	I _B = -2mA			-0.5	V
V _{BE(sat)}	Emitter Saturation Voltage	I _C = -20mA	I _B = -2mA			-0.9	
h _{FE}	Static Forward Current Transfer Ratio	I _C = -1mA	$V_{CE} = -10V^{*}$	25			
		I _C = -10mA	$V_{CE} = -10V^{*}$	40			
		I _C = -30mA	$V_{CE} = -10V^{*}$	25			
f _T	Transition Frequency	V _{CE} = -20V	I _C = -10mA	50			MHz
		f = 20MHz					
C _{obo}	Output Capacitance	V _{CB} = -20V	f = 1MHz			6	pF

* Pulse Test: Pulse Width = 200 μ s, Duty Cycle \leq 2%.

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